



Micro Commercial Components

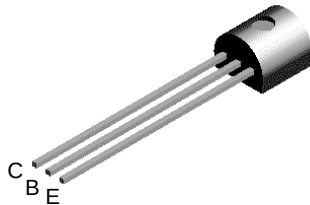
Micro Commercial Components
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S9015

Features

- TO-92 Plastic-Encapsulate Transistors
- Capable of 0.45Watts($T_{amb}=25^{\circ}C$) of Power Dissipation.
- Collector-current 0.1A
- Collector-base Voltage 50V
- Operating and storage junction temperature range: $-55^{\circ}C$ to $+150^{\circ}C$
- Marking Code: S9015

Pin Configuration



Electrical Characteristics @ $25^{\circ}C$ Unless Otherwise Specified

Symbol	Parameter	Min	Max	Units
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OFF CHARACTERISTICS

$V_{(BR)CBO}$	Collector-Base Breakdown Voltage ($I_C=100\mu A$, $I_E=0$)	50	---	Vdc
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage ($I_C=1.0mA$, $I_E=0$)	45	---	Vdc
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage ($I_E=100\mu A$, $I_C=0$)	5.0	---	Vdc
I_{CBO}	Collector Cutoff Current ($V_{CB}=50V$, $I_E=0$)	---	0.05	μA
I_{EBO}	Emitter Cutoff Current ($V_{EB}=5.0V$, $I_C=0$)	---	0.05	μA

ON CHARACTERISTICS

h_{FE}	DC Current Gain ($I_C=1.0mA$, $V_{CE}=5.0V$)	60	1000	---
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage ($I_C=100mA$, $I_E=10mA$)	---	0.3	Vdc
$V_{BE(sat)}$	Base-Emitter Saturation Voltage ($I_C=100mA$, $I_E=10mA$)	---	1.0	Vdc

SMALL-SIGNAL CHARACTERISTICS

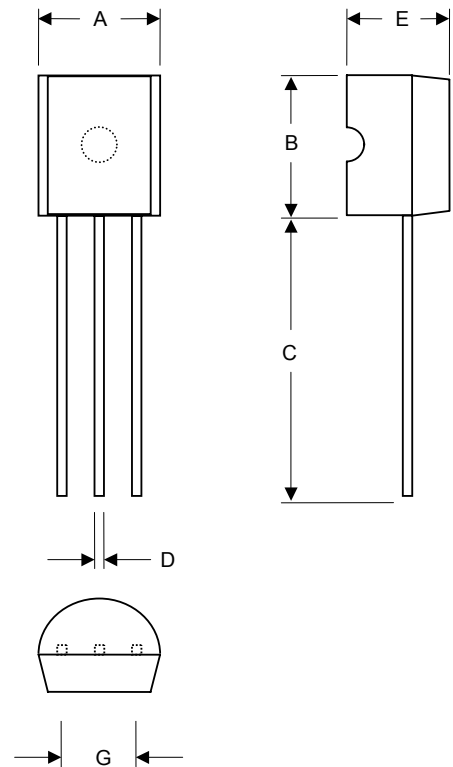
f_T	Transistor Frequency ($I_C=10mA$, $V_{CE}=5.0V$, $f=30MHz$)	150	---	MHz
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CLASSIFICATION OF h_{FE}

Rank	B	C	D
Range	120-200	200-400	400-500

PNP Silicon Transistors

TO-92



DIMENSIONS

DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.170	.190	4.33	4.83	
B	.170	.190	4.30	4.83	
C	.550	.590	13.97	14.97	
D	.010	.020	0.36	0.56	
E	.130	.160	3.30	3.96	
G	.010	.104	2.44	2.64	